# NSN 5961-01-135-1326

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# Inclosure Material:

Metal

# **Overall Length:**

Between 0.115 inches and 0.150 inches

# Terminal Length:

0.500 inches

### **Overall Diameter:**

Between 0.209 inches and 0.230 inches

#### **End Application:**

An/grc-212 13499

#### Internal Configuration:

#### Field effect

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-52

#### **Mounting Method:**

Terminal

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

25.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source

### **Current Rating Per Characteristic:**

24.00 milliamperes zero-gate-voltage drain current and 60.00 milliamperes zero-gate-voltage drain current

## Power Rating Per Characteristic:

500.0 milliwatts total device dissipation

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

### **Terminal Type And Quantity:**

3 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

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